TECHNICAL DATA DATA SHEET 4664, REV. -

HIGH CURRENT HERMETIC SCHOTTKY POWER MODULE

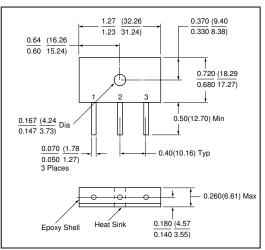
DESCRIPTION: A 45 VOLT, 150/120 AMP, POWER SCHOTTKY RECTIFIER IN A POTTED PACKAGE.

MAXIMUM RATINGS ALL RATINGS ARE @ $T_c = 25 \degree C$ UNLESS OTHERWISE SPECIFI				
RATING	SYMBOL	MAX.	UNITS	
PEAK INVERSE VOLTAGE		45	Volts	
MAXIMUM DC OUTPUT CURRENT @ $T_c=100$ $^{\circ}C$ (P and N versions) (per device)	Ι _ο	150	Amps	
MAXIMUM DC OUTPUT CURRENT @ $T_c=100$ $^{\circ}C$ (Single and D versions) (per device)	Ι _Ο	120	Amps	
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (per leg) (t = 8.3ms, Sine)		1000	Amps	
MAXIMUM JUNCTION CAPACITANCE (V _r =5.0V) (per leg)	Ст	4800	pF	
MAXIMUM THERMAL RESISTANCE	R _{0JC}	0.2	°C/W	
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE		-55 to + 175	°C	

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC				
MAXIMUM FORWARD VOLTAGE DROP, Pulsed	(I _f = 120 Amps) (per leg)			
	T _J = 25 °C	V _f	0.78	Volts
	T _J = 125 °C		0.71	
MAXIMUM REVERSE CURRENT (I _r @ 45 V PIV) (per leg)				
	T _J = 25 °C	l _r	2.4	mA
	T _J = 125 °C		90	

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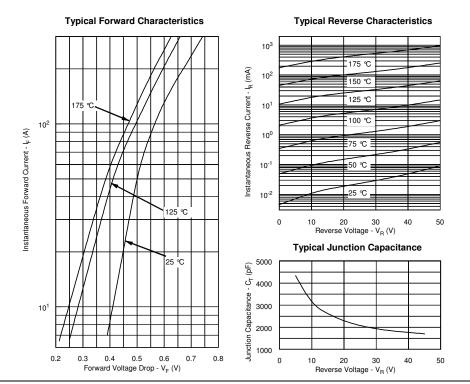
MECHANICAL DIMENSIONS: IN Inches / mm

<u> PKG. 22</u>

PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
DUAL RECTIFIER/COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER/COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER/DOUBLER (D)	ANODE	ANODE/CATHODE	CATHODE

Curves below are for die only



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TECHNICAL DATA

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